## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## MOS FIELD EFFECT TRANSISTORS



2SK2941

# SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### **DESCRIPTION**

This product is n-Chanel MOS Field Effect Transistor designed high current switching application.

#### **FEATURE**

· Low On-Resistance

RDS(on)1 = 14 m $\Omega$  Typ. (VGS = 10 V, ID =18 A) RDS(on)2 = 22 m $\Omega$  Typ. (VGS = 4 V, ID = 18 A)

- Low Ciss Ciss = 1250 pF Typ.
- · Built-in G-S Protection Diode

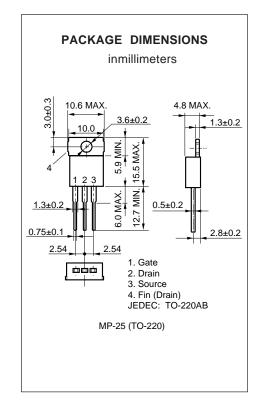
#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

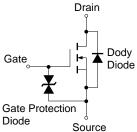
Maximum Voltages and Currents Drain to Source Voltage VDSS 30 V Gate to Source Voltage Vgss ±20 ٧ Drain Current (DC) ±35 ID(DC) Α Drain Current (Pulse)\* ±140 Α ID(Pulse) Maximum Power Dissipation Total Power Dissipation (T<sub>A</sub> = 25 °C) Рτ 1.5 W Total Power Dissipation (Tc = 25 °C) Рτ 60 W Maximum Temperature **Channel Temperature**  $\mathsf{T}_\mathsf{ch}$ 150 °C

Tsta

\* PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

Storage Temperature





The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device acutally used, an additional protection circuit is externally required if voltage exceeding the rated voltage may be applied to this device.

°C

-55 to + 125

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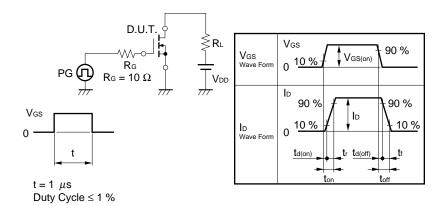




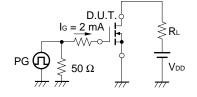
### ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTIC	SYMBLO	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Drain to Source On-State Resistance	RDS(on)1		14	20	mΩ	Vgs = 10 V, ID = 18 A
	RDS(on)2		22	33	mΩ	Vgs = 4 V, Ip = 18 A
Gate to Source Cutoff Voltage	VGS(off)	1.0	1.5	2.0	V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA
Forward Transfer Admittance	l yfs l	8.0	25		S	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 18 A
Drain Leakage Current	IDDS			10	μΑ	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0
Gate to Source Leakage Current	lgss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		1250		pF	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f =1 MHz
Output Capacitance	Coss		900		pF	
Reverse Transfer Capacitance	Crss		460		pF	
Turn-on Delay Time	td(on)		40		ns	$I_D = 18 \text{ A}, \text{ V}_{GS(on)} = 10 \text{ V}$ $V_{DD} = 15 \text{ V}, \text{ R}_G = 10 \Omega$
Rise Time	tr		430		ns	
Turn-off Delay Time	td(off)		160		ns	
Fall Time	tr		220		ns	
Total Gate Charge	Q <sub>G</sub>		50		nC	ID = 35 A, VDD = 24 V, VGS = 10 V
Gate to Source Charge	Qgs		4.5		nC	
Gate to Drain Charge	Q <sub>GD</sub>		21		nC	
Body Diode Forward Voltage	VF(S-D)		1.0		V	IF = 35 A, VGS = 0
Reverse Recovery Time	trr		65		ns	I <sub>F</sub> = 35 A, V <sub>GS</sub> = 0, di/dt = 100 A/μs
Reverse Recovery Charge	Qrr		90		nC	

#### **Test Circuit 1 Switching Time**

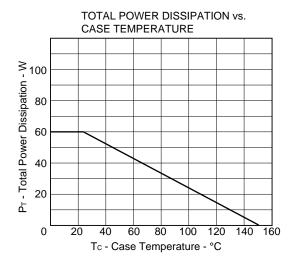


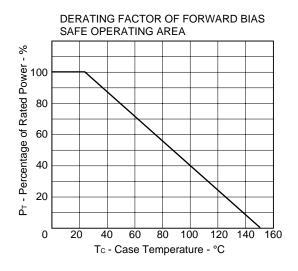
#### Test Circuit 2 Gate Charge

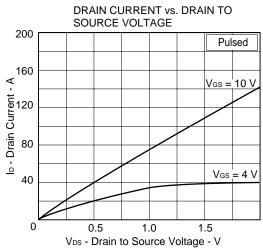


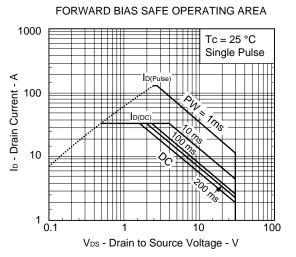


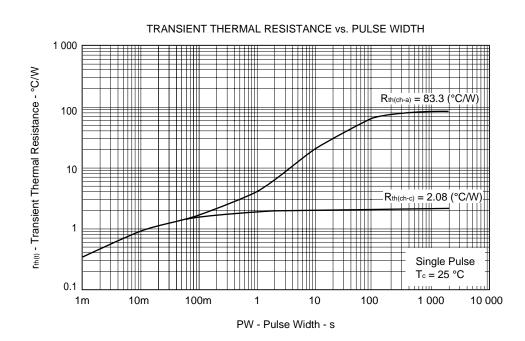
#### ELECTRICAL CHARACTERISTICS (TA = 25 °C)

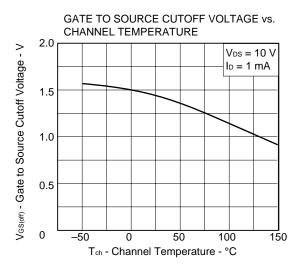


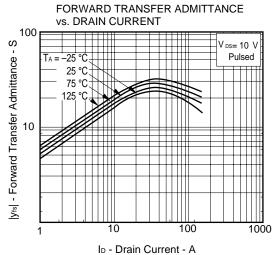


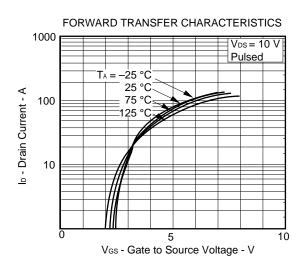


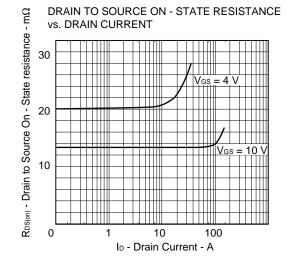


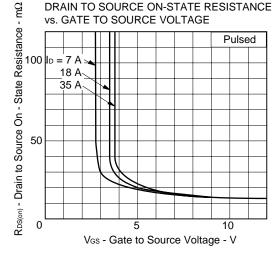


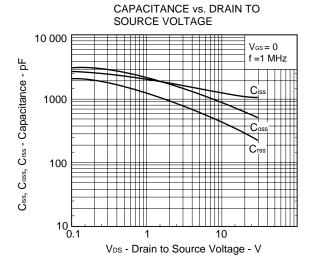




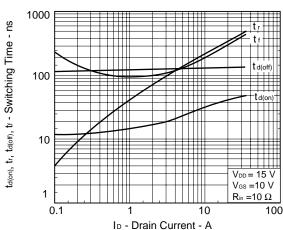


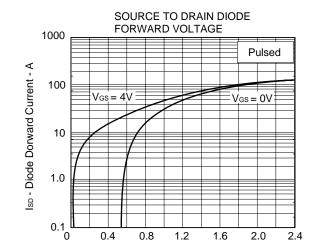




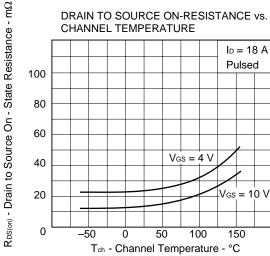


## SWITCHING CHARACTERISTICS



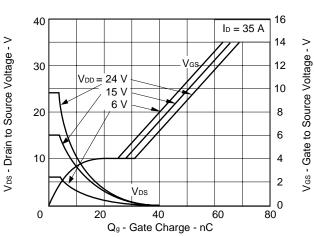


#### DRAIN TO SOURCE ON-RESISTANCE vs. CHANNEL TEMPERATURE

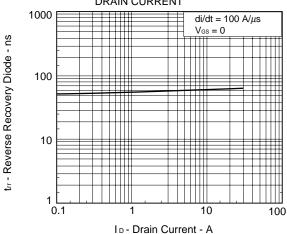


#### DYNAMIC INPUT/OUTPUT CHARACTERISTICS

Vsp - Source to Drain Voltage - V



#### REVERSE RECOVERY TIME vs. DRAIN CURRENT





## ELECTRICAL REFERENCE (TA = 25 °C)

Ducument Name	Ducument No.
NEC semiconductor device reliability/quality control system	C11745E
Quality grade on NEC semiconductor devices	C11531E
Semiconductor device mounting technology manual	C10535E
Semiconductor device package manual	C10943X
Guide to quality assurance for semiconductor devices	MEI-1202
Application circuits using Power MOS FET	TEA-1035
Safe operating area of Power MOS FET	TEA-1037

[MEMO]



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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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Anti-radioactive design is not implemented in this product.